



Effect of Manufacturing Process to Physical Properties of Thermoelectric CuAlO₂ Ceramics

Vo Thanh Tung*, Dung Thi Hoai Trang, Le Tran Uyen Tu, Phan Thi Thao, Le Thi Lien Phuong

Physics Department, University of Sciences, Hue University, 77 Nguyen Hue str., Hue city, Vietnam
E-mail: * vttung@hueuni.edu.vn

Abstract This paper presents the improvement of conventional technology in fabricating of CuAlO₂ thermoelectric materials. The phase CuAlO₂ is formed at 1423K. At higher temperatures, a part of phase CuAlO₂ is separated into Al₂O₃ and CuO. In addition, final materials with improved technology for a single phase, high conductivity and Seebeck coefficient is more stable than materials created with the traditional process.

Keywords CuAlO₂, thermoelectric, creating process

Introduction

Thermoelectric materials can convert thermal energy directly to electrical energy via the Seebeck effect. The performance of the thermoelectric material can be evaluated by the figure of merit, $Z = S^2\sigma / \kappa$, where S , σ and κ are the Seebeck coefficient, electrical conductivity and thermal conductivity, respectively [1]. High thermoelectric efficiency requires high power ($PF = S^2\sigma$) and low thermal conductivity. However, it is difficult to control these parameters independently because Seebeck coefficient is inversely proportional to the electrical conductivity. Besides, when the thermal conductivity was reduced, the electrical conductivity decreased as well. Therefore, the study of thermoelectric materials must aim to increase the electric conductivity and reduce the thermal conductivity. High temperature operation also raised conversion efficiency of thermoelectric system. Further attention has been put on oxide ceramics as thermoelectric materials because they are very suitable for long term use at high temperature in air.

For years, thermoelectric effect have attracted many scientific considerations of both basic researches and applications. The research aims is looking for materials to converting heat energy into electric energy with the highest efficiency. Some oxide systems have been investigated such as Ca₃Co₄O₉ [2], ZnO [3], SrTiO₃ [4],... These materials have many advantages, such as high thermal and chemical stability, low cost, and easy creation. Recently, another metal oxide thermoelectric material, CuAlO₂, also received concentration due to its high temperature stability, high thermoelectric efficiency [5]. Ishiguro et al have extensively studied the crystalline structure of CuAlO₂. Koumoto et al first reported CuAlO₂ with a power factor $\sim 1.04 \times 10^{-4} \text{ Wm}^{-1}\text{K}^{-2}$ for single crystal and $\sim 2.0 \times 10^{-5} \text{ Wm}^{-1}\text{K}^{-2}$ at 1073K for polycrystalline CuAlO₂, respectively [6]. Park and co-workers reported power factors at 1140K for CuAlO₂ ceramics sintered at 1433 K and 1473K, respectively 4.98×10^{-5} and $6.62 \times 10^{-5} \text{ Wm}^{-1}\text{K}^{-2}$ [5]. Therefore, CuAlO₂ ceramics is a promising material for thermoelectric energy conversion applications.

In 2014, CuAlO₂ thermoelectric materials were researched in Hue and achieved some initial results [7]. However, the properties and stability are low as the manufacturing technology has not been fully studied. This



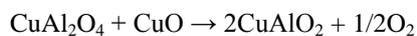
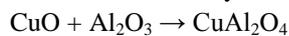
paper presents the improvement of traditional ceramic technology in synthesizing CuAlO_2 thermoelectric materials at Solid State Physics department, College of Science, Hue University.

Materials and Methods

All samples CuAlO_2 were prepared from the reagent – grade powders: CuO (95%, Korea) and Al_2O_3 (98%, Korea). The mixture powders were milled in ethanol for 20 hours. After the powders had been dried, pressed to prepare pellets and calcined at 1073K for 2 hours to create in CuAlO_2 phase. The formed mixture was mill again for 20 hours and pressed into pellets with 100MPa pressure and sintered at 1423K for 2 hours. The specimens for electrical measurements were in the form of rectangular bars of $2 \text{ mm} \times 2 \text{ mm} \times 15 \text{ mm}$. Sintered samples were further annealed at temperature in range $(573 \div 973) \text{ K}$ for 4 hours before analyzing process. The crystalline phase was analyzed using an X – ray diffractometer (XRD, D8 ADVANCE). Thermoelectric properties were analyzed using a thermoelectric system of Nguyen Trong Tinh et al from Institute of Applied Physics and Scientific Instrument of Vietnamese Academy of Science and Technology [8].

Results and Discussion

Phase CuAlO_2 was synthesized from CuO and Al_2O_3 by solid state reaction method following reaction chain [5]:



The XRD profiles of sintered CuAlO_2 were annealing at several temperatures 573K, 673K, 773K, 873K, 973K for 4 hours are shown in Figure 1.

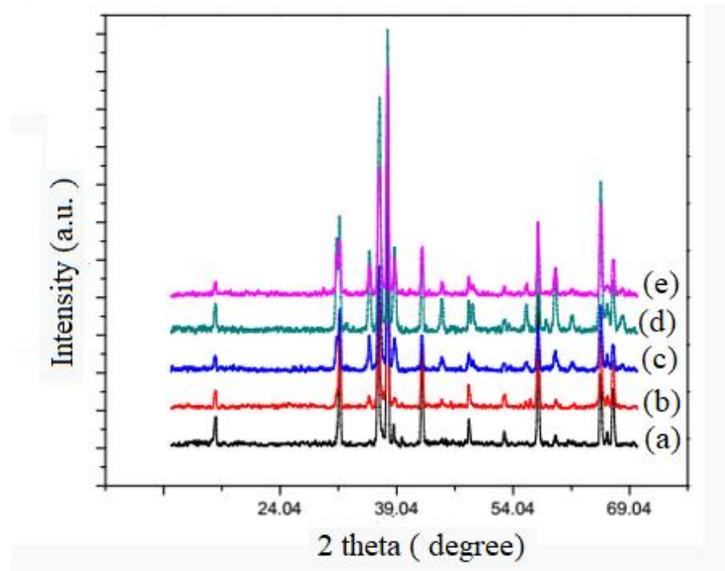


Figure 1: The XRD pattern of the CuAlO_2 sample annealed at the different temperature:

(a) 573K, (b) 673K, (c) 773K, (d) 873K, (e) 973K.

Figure 1 shows X-ray diffraction (XRD) patterns at room temperature with of CuAlO_2 samples annealed at different temperatures of 573 K, 673 K, 773 K, 873 K, and 973 K in 4 hours. It can be seen that annealed CuAlO_2 samples at temperatures of 573 K, 673 K, 773 K, and 873 K the phase of CuAlO_2 was created almost completely, only a very small amount of CuAl_2O_4 exists. However, for the incubation sample at 973 K besides CuAlO_2 phase, there is mainly the appearance of Al_2O_3 , CuO and Cu_2O phase. The ratio of the second phase increased when the annealing temperature was above 873 K. In our opinion, there has been partial separation of CuAlO_2 phase to produce Al_2O_3 and CuO at high annealed temperature. Therefore, the temperature in range from 573 K to 873 K was be chosen for further annealing process.

The material density are listed in Table 1. The temperature dependence of density for CuAlO_2 annealed from 573K and 873K is shown in Figure 2.



Table 1: The influence of CuAlO₂ density (ρ) of on annealing temperature

T (K)	ρ (g/cm ³)
573	4.66
673	4.69
773	4.59
873	4.61

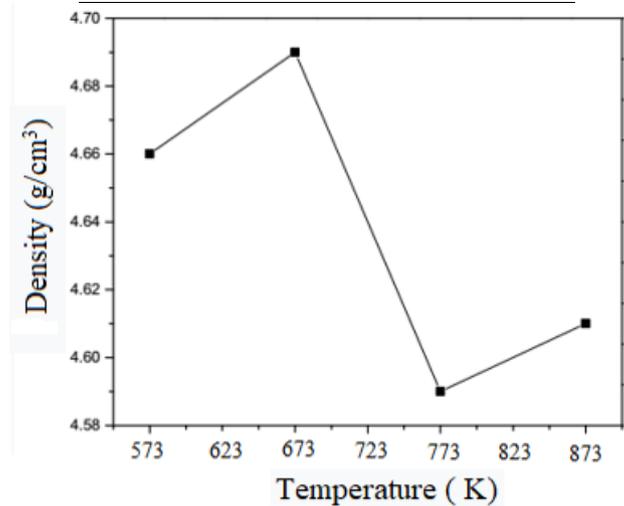
*Figure 2: The annealed temperature dependence of CuAlO₂ densities*

Table 1 shows that the ceramic density increases when the annealing temperature rises and reaches a highest value at 673K. Then, the density decreases with further increasing annealing temperature. According to the structural analysis, with annealing temperatures above 873K, a part of CuAlO₂ material is split into CuO and Al₂O₃. The percentage of these phases increases more with higher annealing temperature, causing the homogeneity of chemical composition in materials. This may cause a decrease in the proportion of ceramics when the annealing temperature is increased after sintering.

To investigate the temperature dependence of thermoelectric properties, we survey about the variation of thermoelectric parameters at different annealing temperature.

Figure 3 shows the variation of resistivity for CuAlO₂ ceramics with several annealing temperatures at 773K, 873K, and 973K.

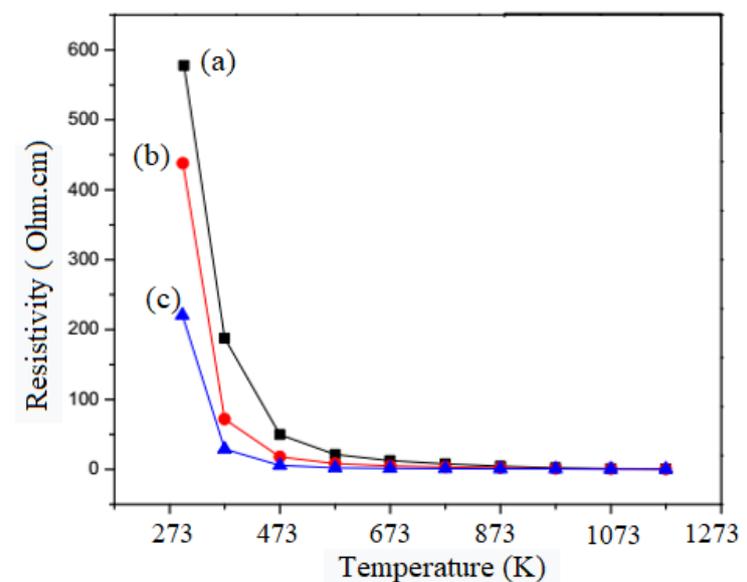
*Figure 3: The temperature dependence of resistivity in CuAlO₂ annealed at (a) 773K, (b) 873K, (c) 973K*

Figure 3 shows that the resistivity of the sample decreases with increasing annealing temperature. The higher annealing temperature, the lower resistivity is. Thus, the annealing temperature affects thermoelectric properties of sintered CuAlO_2 ceramics.

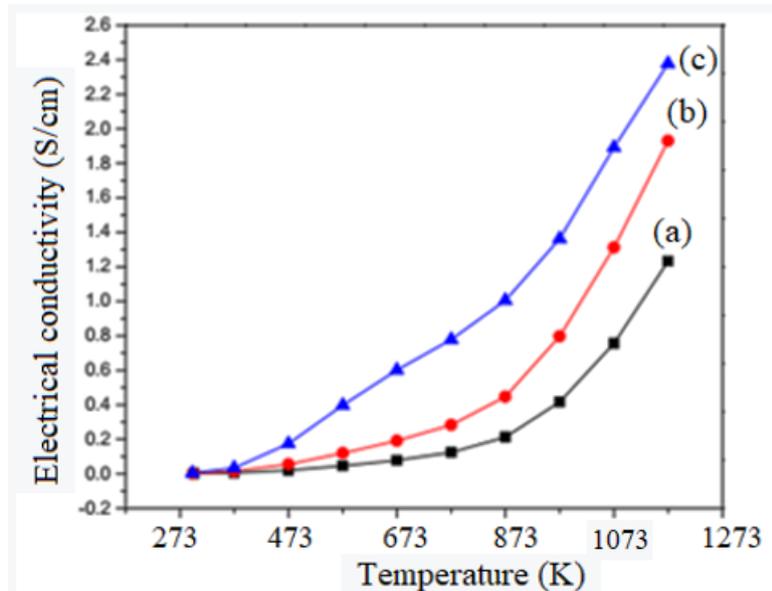


Figure 4: The temperature dependence of electrical conductivity in CuAlO_2 annealed at (a) 773K, (b) 873K, (c) 973K.

Figure 4 indicated when the annealing temperature increase, the electrical conductivity of the material increases. However, the speed and value of the electrical conductivity of the sample annealed at 973K is much larger than that at 773K and 873K. It is possibly because in range of annealed temperatures above 873K, a part of CuAlO_2 material is split into CuO and Al_2O_3 . Thus, it can be asserted that annealing temperatures affect the electrical conductivity of sintered CuAlO_2 thermoelectric ceramics.

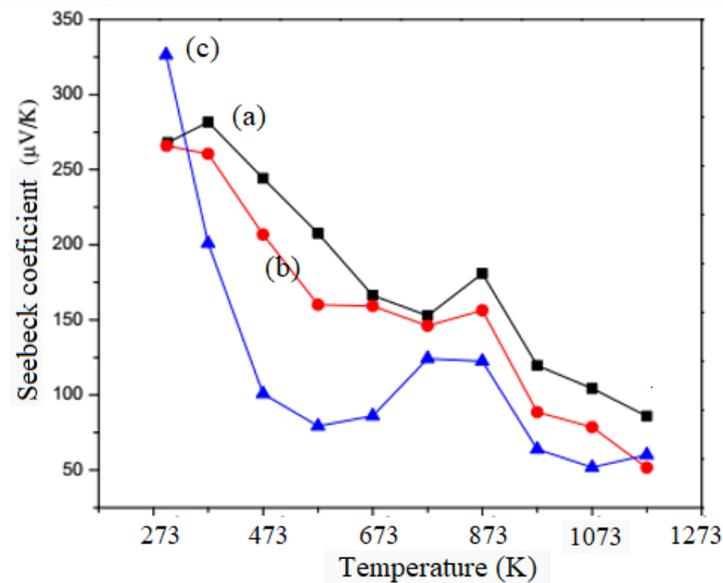


Figure 5: Seebeck coefficient of CuAlO_2 samples as a function of annealing temperature at (a) 773K, (b) 873K, (c) 973K

The variation of Seebeck coefficients with temperature of CuAlO_2 ceramics annealed at 773K, 873K, and 973K. Accordingly, the values of the Seebeck coefficient in CuAlO_2 samples annealed at higher temperature tend to decrease. Especially, at 773K annealing temperature, the variation of Seebeck coefficient with temperature

reaches the maximum value. On the contrary, phase separation is a significant impact on the thermoelectric properties of the ceramic in high temperature range.

Conclusion

By solid state reaction method and improvement process, we have synthesized the CuAlO_2 ceramics at different further annealed temperatures. The annealing temperature were chosen in range from 673K to 873K. At this temperature range, it is possible to obtain a single phase ceramics, with higher electrical conductivity and more stable Seebeck coefficient than that made by conventional method.

References

- [1]. H.J. Goldsmid. (1995). CRC Handbook of Thermoelectrics: *Conversion Energy and Figure of Merit*, edited by D. M. Rowe, CRC Press LLC, Boca Raton.
- [2]. A.C. Masset, C. Michel, A. Maignan, M. Hervieu, O. Toulemonde, F. Studer, B. Raveau, J. Hejtmanek. (2000). Misfit-layered cobaltite with an anisotropic giant magnetoresistance: $\text{Ca}_3\text{Co}_4\text{O}_9$. *Phys. Rev. B* 62, 166–175.
- [3]. M. Ohtaki; T. Tsubota, K. Eguchi, H. Arai. (1996). High-temperature thermoelectric properties of $(\text{Zn}_{1-x}\text{Al}_x)\text{O}$. *J. Appl. Phys.*, 79, 1816–1818.
- [4]. S. Ohta, H. Ohta, K. Koumoto. (2006). Grain size dependence of thermoelectric performance of Nb doped SrTiO_3 polycrystals. *J. Ceram. Soc. Jpn.*, 114, 102–105.
- [5]. K. Park, K.Y. Ko, W.S. Seo. (2005). Thermoelectric properties of CuAlO_2 . *Journal of the European Ceramic Society*, 25, 2219–2222.
- [6]. K. Koumoto, H. Koduka, W.S. Seo. (2001). *J. Mater. Chem.*, 11, 251–252.
- [7]. Lê Nguyễn Lan Chi. (2015). *Chế tạo và nghiên cứu tính chất vật lý của gốm nhiệt điện CuAlO_2* . Luận văn Thạc sĩ Vật lý, Trường Đại học Khoa học Huế.
- [8]. Lê Thị Thu Hương. (2011). *Xây dựng phương pháp đo tính chất nhiệt điện của vật liệu ở nhiệt độ cao*. Luận văn Thạc sĩ Vật lý, Trường Đại học Khoa học Tự nhiên, Đại học Quốc gia Hà Nội.

